

SOT-227 Power Module Insulated Standard Recovery Rectifier, 160 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} per module	160 A, T _C = 101 °C					
V _{FM} typical at 100 A	1.16 V					
Type	Modules - diode, high voltage					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

FEATURES

- Two fully independent diodes
- Fully insulated package



 High voltage rectifiers optimized for very low forward voltage drop

- Industry standard outline
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

These devices are intended for use in main rectification. Single or three phase bridge.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	90 °C	91				
I _{F(RMS)}		138	Δ.			
I _{FSM}	50 Hz	940	A			
	60 Hz	985				
101	50 Hz	4420	A ² s			
l ² t	60 Hz	4015	A-S			
I ² √t		44 180	A ² √s			
V _{RRM}		1200	V			
TJ		-55 to +150	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{RRM,} MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} TYPICAL AT 150 °C mA					
VS-RA160FA120	120	1200	1300	1.0					



FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CON	VALUES	UNITS	
Maximum average forward current at case temperature per leg	I _{F(AV)}	180° condu	180° conduction, half sine wave, 90 °C			А
Maximum RMS forward current per leg	I _{F(RMS)}	DC at 101 °	°C case temper	ature	138	
		t = 10 ms	No voltage		940	
Maximum peak, one-cycle forward,	1	t = 8.3 ms	reapplied		985	A
non-repetitive surge current per leg	I _{FSM}	t = 10 ms	100 % V _{RRM}	O's as 'station if	790	
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	825	
		t = 10 ms	No voltage		4420	A ² s
Maximum I ² t for fusing per leg	l²t	t = 8.3 ms	reapplied		4015	
Maximum 1-t for fusing per leg		t = 10 ms	100 % V _{RRM}		3125	
		t = 8.3 ms	reapplied		2840	
Maximum I ² √t for fusing per leg	l²√t	t = 0.1 ms t	o 10 ms, no vo	Itage reapplied	44 180	A²√s
Low level of threshold voltage per leg	V _{F(TO)1}	/16 7 0/ v =		v.l. T. T. massimsum	0.80	V
Low level value of forward slope resistance	r _{f1}	$(16.7 \% \times \pi \times I_{F(AV)}) < I < \pi \times I_{F(AV)}, T_J = T_J \text{ maximum}$			4.32	mΩ
High level of threshold voltage per leg	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.93	V
High level value of forward slope resistance	r _{f2}				4.14	mΩ
Maximum forward voltage drep nor les		I _{FM} = 100 A, T _J = 25 °C		1.27	V	
Maximum forward voltage drop per leg	V_{FM}	I _{FM} = 100 A, T _J = 150 °C				1.22

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse leakage current	1	T _J = 25 °C	150	μA
per leg	IRRM	T _J = 150 °C	1.5	mA
RMS insulation voltage	V _{INS}	T _J = 25 °C, any terminal to case, t = 1 minute	2500	V

THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS		
Thermal resistance,	per leg	D	-	-	0.26			
junction to case	per module	R _{thJC}	-	-	0.13	°C/W		
Thermal resistance, case to heatsink	per module	R _{thCS}	-	0.1	-			
Weight			-	30	-	g		
Mounting torque to terminal			-	-	1.1 (9.7)	Nm (lbf. in)		
Mounting torque to heatsink			-	-	1.8 (15.9)	Nm (lbf. in)		
Case style			SOT-227					

AR CONDUCTION PER JUNCTION											
DEVICE	S	INE HALF	WAVE CO	NDUCTIO	N	REC	CTANGULA	AR WAVE	CONDUCT	NOI	UNITS
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	°C/W
VS-RA160FA120	0.109	0.122	0.149	0.213	0.355	0.069	0.119	0.159	0.223	0.358	C/VV

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Vishay Semiconductors

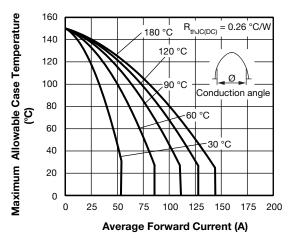


Fig. 1 - Current Ratings Characteristics (A)

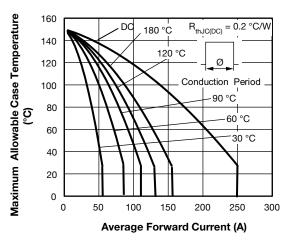


Fig. 2 - Current Ratings Characteristics (A)

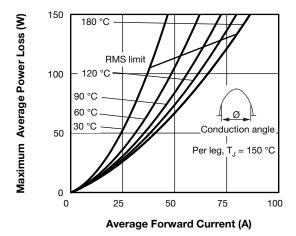


Fig. 3 - Current Ratings Characteristics (A)

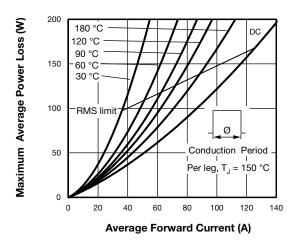


Fig. 4 - Forward Power Loss Characteristics

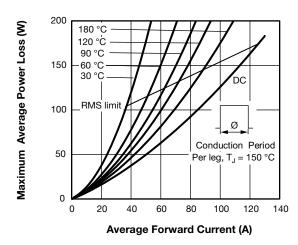


Fig. 5 - Forward Power Loss Characteristics

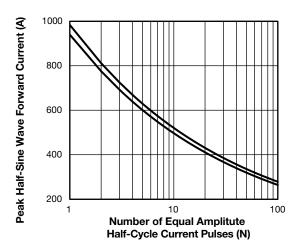


Fig. 6 - Maximum Non-Repetitive Surge Current

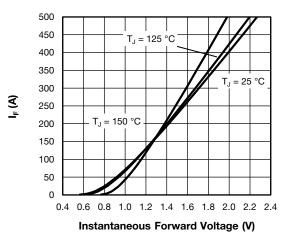


Fig. 7 - Typical Forward Voltage Characteristics

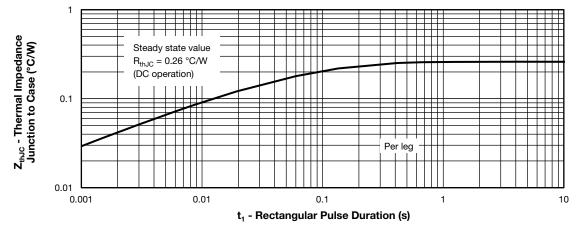


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VS-R Α 160 F 120 Α 3 5 2 4 (6) Vishay Semiconductors product Standard recovery diode Present silicon generation Current rating (160 = 160 A) Circuit configuration (2 separate diodes, parallel pin-out) Package indicator (SOT-227 standard insulated base) Voltage rating (120 = 1200 V)

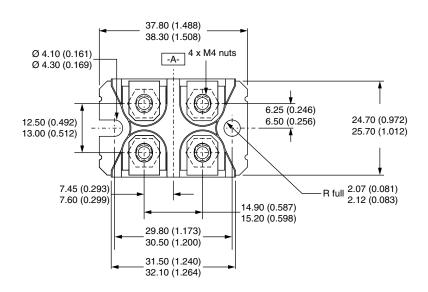


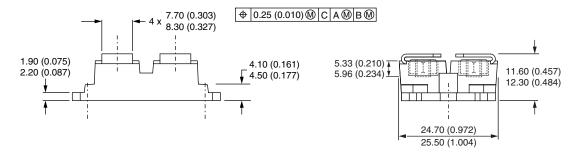
CIRCUIT CONFIGURATION							
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING					
Two separate diodes, parallel pin-out	F	Lead Assignment 4					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425				

SOT-227 Generation 2

DIMENSIONS in millimeters (inches)





Note

· Controlling dimension: millimeter



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